

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1 kV
- Very low Drain-Source on-state resistance R_{DSon} = 34 mΩ
- Very low threshold voltage of 0.65 V for portable applications

3. Applications

- Low-side load switch and charging switch for portable devices
- Power management in battery-driven portables
- LED driver
- DC-to-DC converters

4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	12	V
V _{GS}	gate-source voltage	_		-8	-	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	-	3.2	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 3.2 A; T _j = 25 °C		-	34	45	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	4 3	G (The second s
4	D	drain		
			Transparent top view DFN1010D-3 (SOT1215)	S 017aaa255

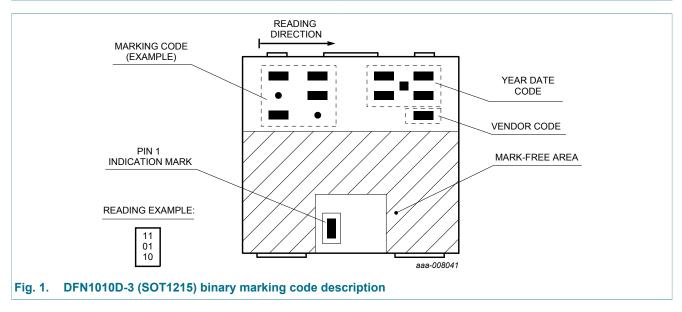
6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMXB40UNE	DFN1010D-3	DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMXB40UNE	10 00 00



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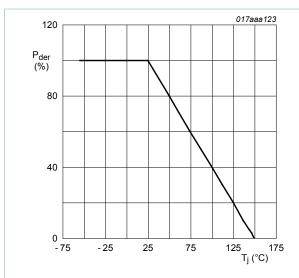
8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit		
V _{DS}	drain-source voltage	T _j = 25 °C		-	12	V		
V _{GS}	gate-source voltage			-8	8	V		
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C	[1]	-	3.2	А		
		V_{GS} = 4.5 V; T_{amb} = 100 °C	[1]	-	2.5	А		
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	15	А		
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	0.4	W		
			[1]	-	1.07	W		
		T _{sp} = 25 °C		-	8.33	W		
Tj	junction temperature			-55	150	°C		
T _{amb}	ambient temperature			-55	150	°C		
T _{stg}	storage temperature			-65	150	°C		
Source-dra	Source-drain diode							
I _S	source current	T _{amb} = 25 °C	[1]	-	1	А		

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.





$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

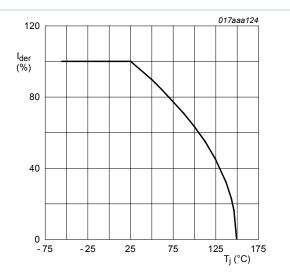


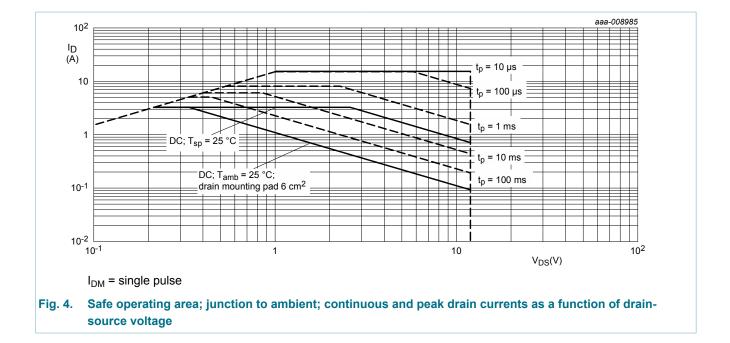
Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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9. Thermal characteristics

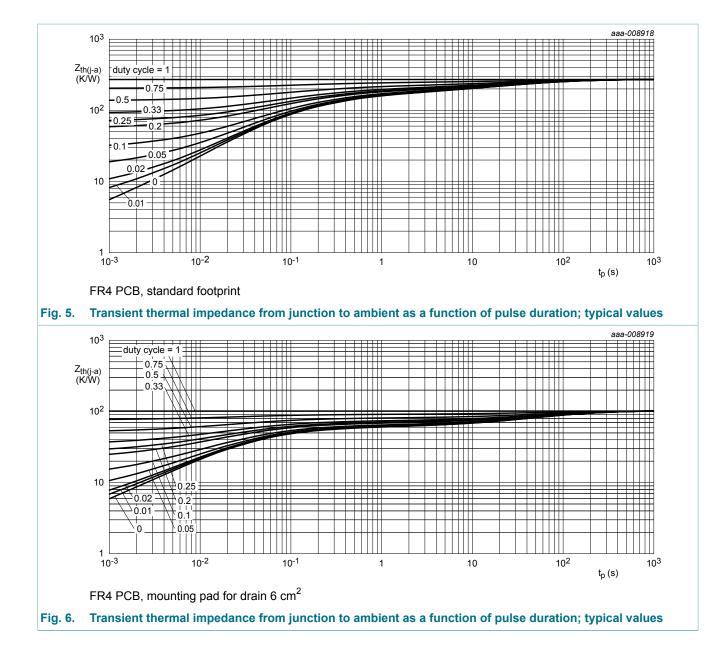
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance in from junction to ambient	in free air	[1]	-	271	311	K/W
			[2]	-	102	117	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



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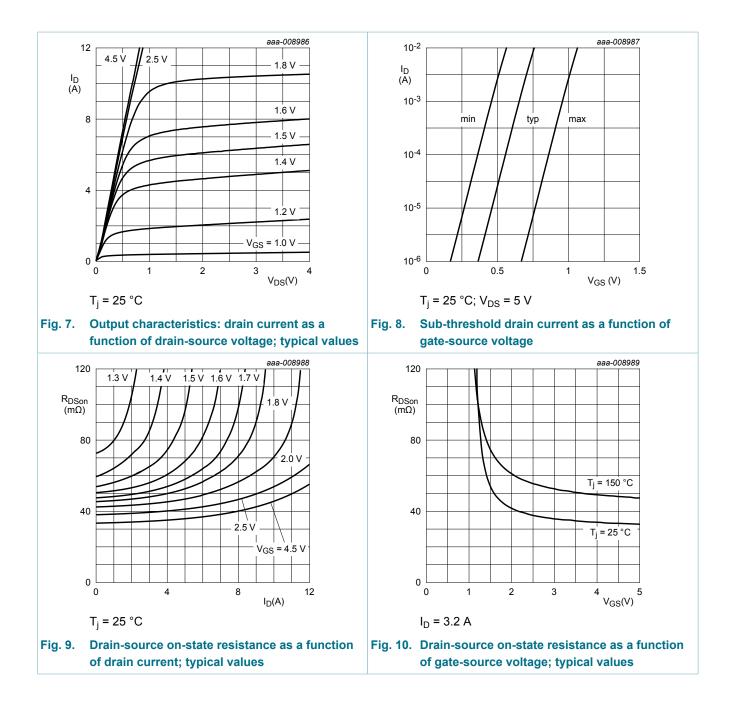


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara				-71-		
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	12	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.4	0.65	0.9	V
I _{DSS}	drain leakage current	V_{DS} = 12 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
R _{DSon}	drain-source on-state	V_{GS} = 4.5 V; I _D = 3.2 A; T _j = 25 °C	-	34	45	mΩ
	resistance	V_{GS} = 4.5 V; I _D = 3.2 A; T _j = 150 °C	-	49	67	mΩ
		V_{GS} = 2.5 V; I _D = 3.2 A; T _j = 25 °C	-	39	64	mΩ
		V _{GS} = 1.8 V; I _D = 1 A; T _j = 25 °C	-	46	85	mΩ
		V_{GS} = 1.5 V; I _D = 0.1 A; T _j = 25 °C	-	50	100	mΩ
		V_{GS} = 1.2 V; I _D = 1 mA; T _j = 25 °C	-	121	-	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 2 A; T _j = 25 °C	-	1.2	-	S
R _G	gate resistance	f = 1 MHz	-	1	-	Ω
Dynamic ch	aracteristics	1	I			
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 3.2 A; V _{GS} = 4.5 V;	-	6.6	11.6	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.6	-	nC
Q _{GD}	gate-drain charge		-	1.7	-	nC
C _{iss}	input capacitance	V_{DS} = 10 V; f = 1 MHz; V_{GS} = 0 V;	-	556	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	107	-	pF
C _{rss}	reverse transfer capacitance	_	-	94	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; I _D = 3.2 A; V _{GS} = 4.5 V;	-	6	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	21	-	ns
t _{d(off)}	turn-off delay time		-	18	-	ns
t _f	fall time		-	9	-	ns
Source-drai	in diode	,	· · ·			
V _{SD}	source-drain voltage	I _S = 1 A; V _{GS} = 0 V; T _j = 25 °C	-	0.8	1.2	V

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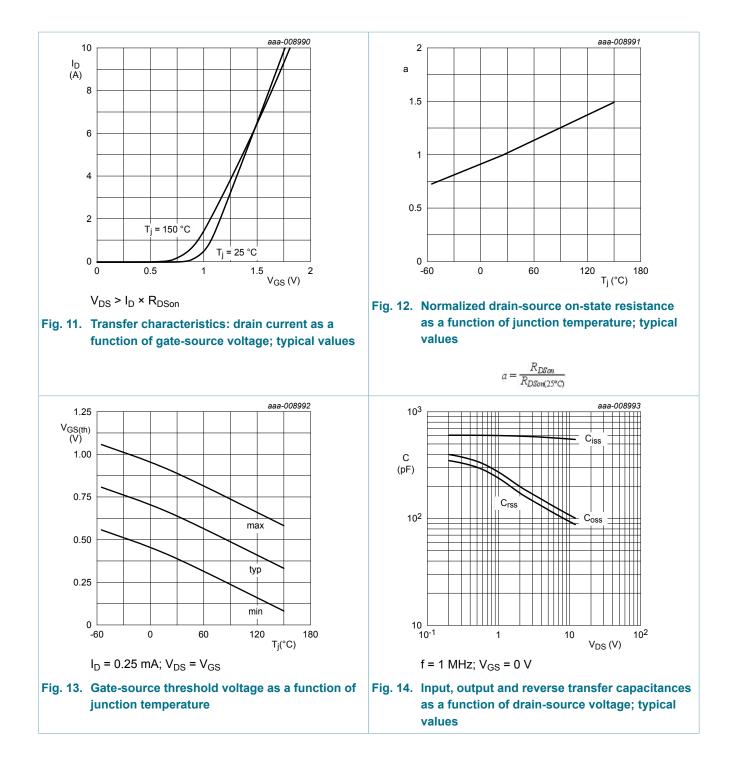
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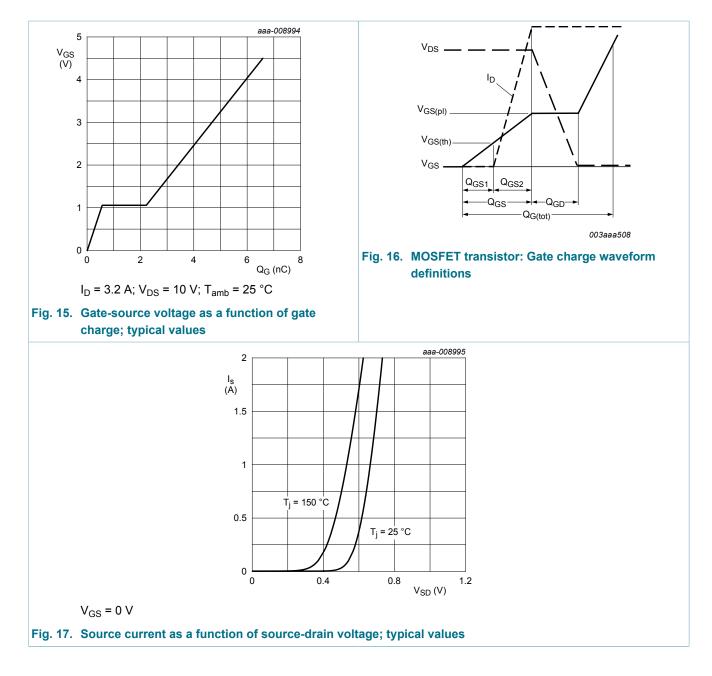
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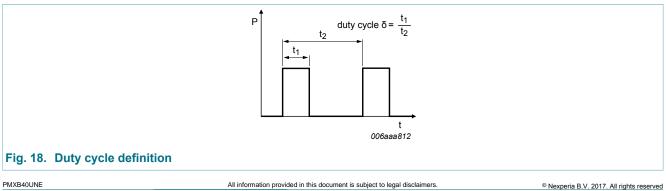
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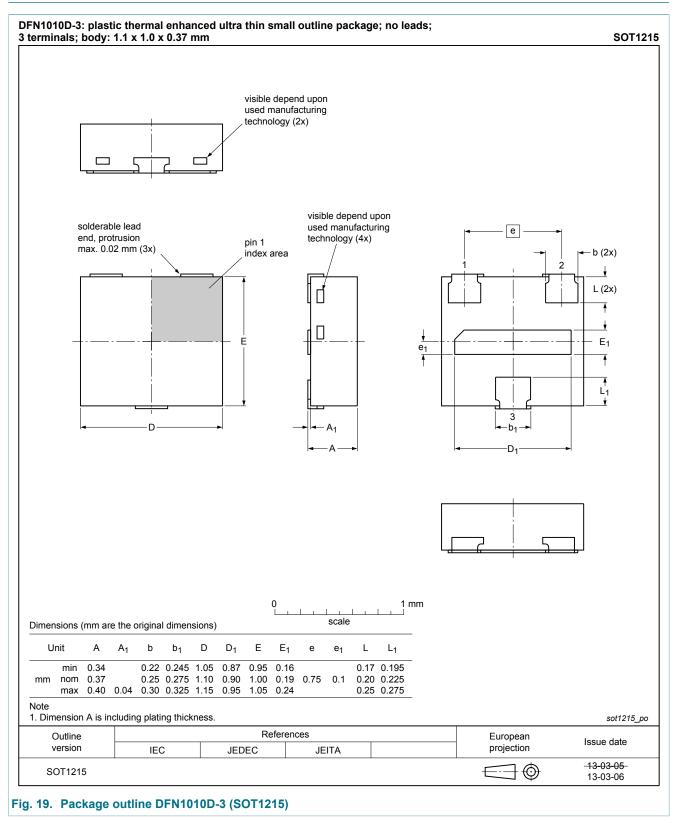
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11. Test information



12. Package outline

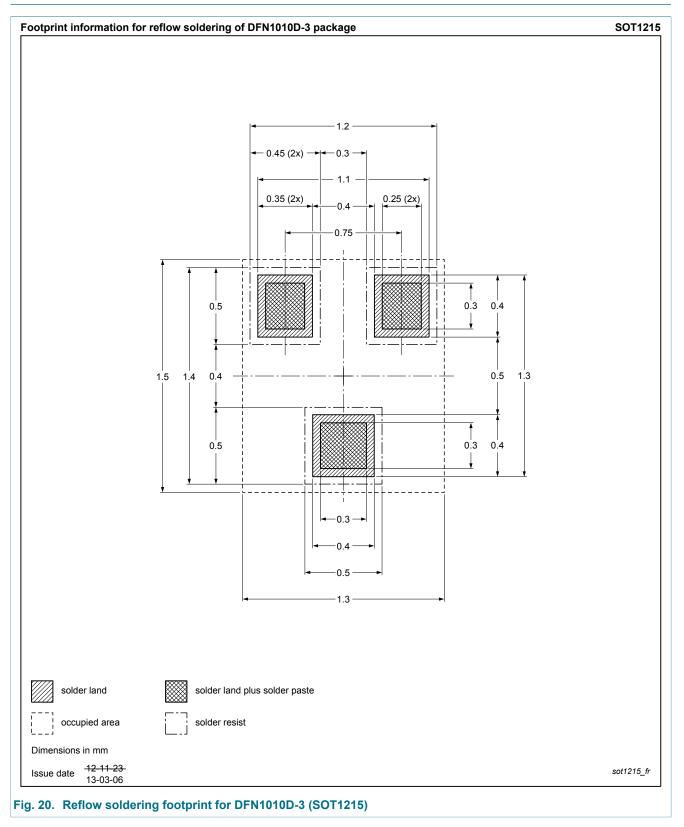


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13. Soldering



14. Revision history

Table 8. Revision his	able 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMXB40UNE v.1	20130927	Product data sheet	-	-			

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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